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FEATURES

Charge pump with automatic gain selection of 1×, 1.5×, and 2× for maximum efficiency

7 independent, programmable LED drivers

7 drivers capable of 30 mA (typical)

1 driver also capable of 60 mA (typical)

Programmable maximum current limit (128 levels)

Standby mode for <1 μA current consumption

16 programmable fade in and fade out times

0.1 sec to 5.5 sec

Choose from linear, square, or cubic rates

Fading override

I²C-compatible interface for all programming

Dedicated reset pin and built-in power-on reset (POR)

Short-circuit, overvoltage, and overtemperature protection

Internal soft start to limit inrush currents

Input-to-output isolation during faults or shutdown

Operation down to $V_{IN} = 2.5$ V with undervoltage lockout (UVLO) at $V_{IN} = 2.0$ V

Available in a small 20-ball, 2.15 mm × 2.36 mm × 0.6 mm

WLCSF or a 20-lead, 4 mm × 4 mm × 0.75 mm LFCSP

APPLICATIONS

Mobile display backlighting

Mobile phone keypad backlighting

Dual RGB backlighting

LED indication

General backlighting of small format displays

GENERAL DESCRIPTION

The ADP8861 provides a powerful charge pump driver with independent control of up to seven LEDs. These seven LEDs can be independently driven up to 30 mA (typical). The seventh LED can also be driven to 60 mA (typical). All LEDs are programmable for maximum current and fade in/out times via the I²C interface. These LEDs can also be combined into groups to reduce the processor instructions during fade in/out.

TYPICAL OPERATING CIRCUIT

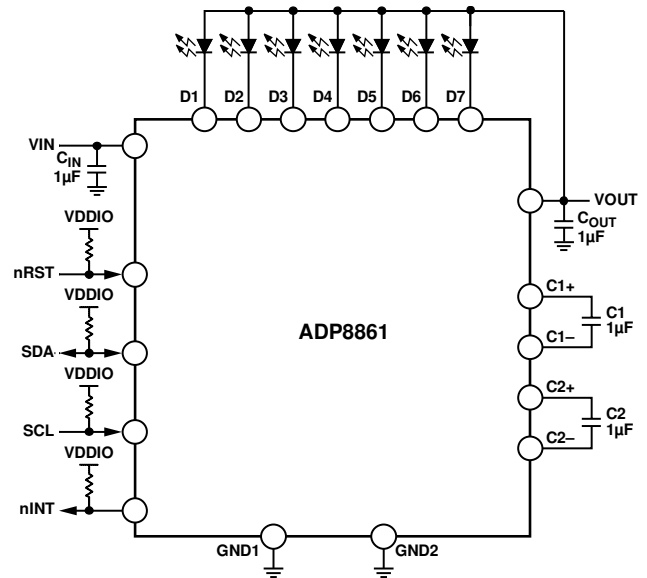


Figure 1.

08391-001

This entire configuration is driven by a two-capacitor charge pump with gains of 1×, 1.5×, and 2×. The charge pump is capable of driving a maximum I_{OUT} of 240 mA from a supply of 2.5 V to 5.5 V. A full suite of safety features, including short-circuit, overvoltage, and overtemperature protection, allows easy implementation of a safe and robust design. Additionally, input inrush currents are limited via an integrated soft start combined with controlled input-to-output isolation.

ADP8861* PRODUCT PAGE QUICK LINKS

Last Content Update: 03/03/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- ADP8861 Evaluation Board

DOCUMENTATION

Data Sheet

- ADP8861: Charge Pump, 7-Channel Smart LED Driver with I2C Interface Data Sheet

User Guides

- UG-005: Software User Guide

SOFTWARE AND SYSTEMS REQUIREMENTS

- ADP8860 Back-light LED Linux Driver

DESIGN RESOURCES

- ADP8861 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all ADP8861 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

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REVISION HISTORY

2/2017—Rev. B to Rev. C

Updated Outline Dimensions	39
Changes to Ordering Guide	40

4/2012—Rev. A to Rev. B

Changes to Table 1	4
Updated Outline Dimensions	40
Changes to Ordering Guide	40

6/2010—Rev. 0 to Rev. A

Changes to Features Section and General Description Section ..	1
Changes to Thermal Resistance Section and Table 3	5
Added Figure 4; Renumbered Sequentially	6
Changes to Table 4	6
Changes to Layout Guidelines Section	19
Updated Outline Dimensions	39
Changes to Ordering Guide	40

4/2010—Revision 0: Initial Version

SPECIFICATIONS

$V_{IN} = 3.6\text{ V}$, $SCL = 2.7\text{ V}$, $SDA = 2.7\text{ V}$, $nINT = \text{open}$, $nRST = 2.7\text{ V}$, $V_{D1:D7} = 0.4\text{ V}$, Capacitor $C1 = 1\text{ }\mu\text{F}$, Capacitor $C2 = 1\text{ }\mu\text{F}$, $C_{OUT} = 1\text{ }\mu\text{F}$, typical values are at $T_A = 25^\circ\text{C}$ and are not guaranteed, minimum and maximum limits are guaranteed from $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, unless otherwise noted.

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
SUPPLY						
Input Voltage						
Operating Range	V_{IN}		2.5		5.5	V
Start-Up Level	$V_{IN(START)}$	V_{IN} increasing		2.05	2.30	V
Low Level	$V_{IN(STOP)}$	V_{IN} decreasing	1.75	1.97		V
$V_{IN(START)}$ Hysteresis	$V_{IN(HYS)}$	After startup		80		mV
UVLO Noise Filter	t_{UVLO}			10		μs
Quiescent Current	I_Q					
Prior to $V_{IN(START)}$	$I_{Q(START)}$	$V_{IN} = V_{IN(START)} - 100\text{ mV}$		10		μA
During Standby	$I_{Q(STBY)}$	$V_{IN} = 3.6\text{ V}$, Bit $nSTBY = 0$, $SCL = SDA = 0\text{ V}$		0.3	1.0	μA
After Startup and Switching	$I_{Q(ACTIVE)}$	$V_{IN} = 3.6\text{ V}$, Bit $nSTBY = 1$, $I_{OUT} = 0\text{ mA}$, gain = $2\times$		4.5	7.2	mA
OSCILLATOR						
Switching Frequency	f_{SW}	Charge pump gain = $2\times$	0.8	1	1.32	MHz
Duty Cycle	D			50		%
OUTPUT CURRENT CONTROL						
Maximum Drive Current	$I_{D1:D7(MAX)}$	$V_{D1:D7} = 0.4\text{ V}$				
Diode 1 to Diode 7		Bit SCR = 0 in the ISC7 register				
$T_J = 25^\circ\text{C}$			26.2	30	34.1	mA
$T_J = -40^\circ\text{C}$ to $+85^\circ\text{C}$			24.4		34.1	mA
Diode 7 Only (60 mA Setting)	$I_{D7(60\text{ mA})}$	$V_{D7} = 0.4\text{ V}$, Bit SCR = 1 in the ISC7 register				
$T_J = 25^\circ\text{C}$			52.5	60	67	mA
$T_J = -40^\circ\text{C}$ to $+85^\circ\text{C}$			48.8		67	mA
LED Current Source Matching ¹	I_{MATCH}					
All Current Sinks	I_{MATCH7}	$V_{D1:D7} = 0.4\text{ V}$		2.0		%
Diode 2 to Diode 7 Current Sinks	I_{MATCH6}	$V_{D2:D7} = 0.4\text{ V}$		1.5		%
Leakage Current on LED Pins	$I_{D1:D7(LKG)}$	$V_{IN} = 5.5\text{ V}$, $V_{D1:D7} = 2.5\text{ V}$, Bit $nSTBY = 1$			0.5	μA
Equivalent Output Resistance	R_{OUT}					
Gain = $1\times$		$V_{IN} = 3.6\text{ V}$, $I_{OUT} = 100\text{ mA}$		0.5		Ω
Gain = $1.5\times$		$V_{IN} = 3.1\text{ V}$, $I_{OUT} = 100\text{ mA}$		3.0		Ω
Gain = $2\times$		$V_{IN} = 2.5\text{ V}$, $I_{OUT} = 100\text{ mA}$		3.8		Ω
Regulated Output Voltage	$V_{OUT(REG)}$	$V_{IN} = 3\text{ V}$, gain = $2\times$, $I_{OUT} = 10\text{ mA}$	4.3	4.9	5.5	V
AUTOMATIC GAIN SELECTION						
Minimum Voltage						
Gain Increases	$V_{HR(UP)}$	Decrease $V_{D1:D7}$ until the gain switches up	162	200	276	mV
Minimum Current Sink Headroom Voltage	$V_{HR(MIN)}$	$I_{DX} = I_{DX(MAX)} \times 95\%$		180		mV
Gain Delay	t_{GAIN}	The delay after gain has changed and before gain is allowed to change again		100		μs

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
FAULT PROTECTION						
Start-Up Charging Current Source	I_{SS}	$V_{IN} = 3.6\text{ V}, V_{OUT} = 0.8 \times V_{IN}$	2.5	3.75	5.5	mA
Output Voltage Threshold	V_{OUT}					
Exit Soft Start	$V_{OUT(START)}$	V_{OUT} rising		$0.92 \times V_{IN}$		V
Short-Circuit Protection	$V_{OUT(SC)}$	V_{OUT} falling		$0.55 \times V_{IN}$		V
Output Overvoltage Protection	V_{OVP}					
Activation Level				5.8		V
OVP Recovery Hysteresis				500		mV
Thermal Shutdown						
Threshold	TSD			150		°C
Hysteresis	$TSD_{(HYS)}$			20		°C
Isolation from Input to Output During Fault	I_{OUTLKG}	$V_{IN} = 5.5\text{ V}, V_{OUT} = 0\text{ V}, \text{Bit } nSTBY = 0$			1.5	μA
Time to Validate a Fault	t_{FAULT}			2		μs
I²C INTERFACE						
Operating V_{DDIO} Voltage	V_{DDIO}				5.5	V
Logic Low Input ²	V_{IL}	$V_{IN} = 2.5\text{ V}$			0.5	V
Logic High Input ³	V_{IH}	$V_{IN} = 5.5\text{ V}$	1.55			V
I²C TIMING SPECIFICATIONS						
Delay from Reset Deassertion to I ² C Access	t_{RESET}	Guaranteed by design			20	μs
SCL Frequency	f_{SCL}				400	kHz
SCL High Time	t_{HIGH}		0.6			μs
SCL Low Time	t_{LOW}		1.3			μs
Setup Time						
Data	$t_{SU, DAT}$		100			ns
Repeated Start	$t_{SU, STA}$		0.6			μs
Stop Condition	$t_{SU, STO}$		0.6			μs
Hold Time						
Data	$t_{HD, DAT}$		0		0.9	μs
Start/Repeated Start	$t_{HD, STA}$		0.6			μs
Bus Free Time (Stop and Start Conditions)	t_{BUF}		1.3			μs
Rise Time (SCL and SDA)	t_R		$20 + 0.1 C_B$		300	ns
Fall Time (SCL and SDA)	t_F				300	ns
Pulse Width of Suppressed Spike	t_{SP}		0		50	ns
Capacitive Load per Bus Line	C_B				400	pF

¹ Current source matching is calculated by dividing the difference between the maximum and minimum currents from the sum of the maximum and minimum.

² V_{IL} is a function of the input voltage. See Figure 16 in the Typical Performance Characteristics section for typical values over operating ranges.

³ V_{IH} is a function of the input voltage. See Figure 16 in the Typical Performance Characteristics section for typical values over operating ranges.

I²C TIMING DIAGRAM

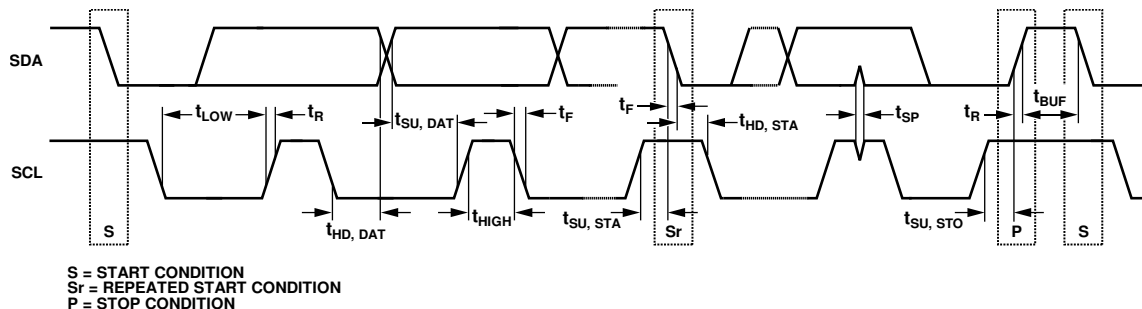


Figure 2. I²C Interface Timing Diagram

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ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
VIN, VOUT	−0.3 V to +6 V
D1, D2, D3, D4, D5, D6, and D7	−0.3 V to +6 V
nINT, nRST, SCL, and SDA	−0.3 V to +6 V
Output Short-Circuit Duration	Indefinite
Operating Temperature Range	
Ambient (T _A)	−40°C to +85°C ¹
Junction (T _J)	−40°C to +125°C
Storage Temperature Range	−65°C to +150°C
Soldering Conditions	JEDEC J-STD-020
ESD (Electrostatic Discharge)	
Human Body Model (HBM)	±3 kV
Charged Device Model (CDM)	±1.5 kV

¹ The maximum operating junction temperature (T_{J(MAX)}) takes precedence over the maximum operating ambient temperature (T_{A(MAX)}). See the Maximum Temperature Ranges section for more information.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Absolute maximum ratings apply individually only, not in combination. Unless otherwise specified, all voltages are referenced to ground.

MAXIMUM TEMPERATURE RANGES

The maximum operating junction temperature (T_{J(MAX)}) takes precedence over the maximum operating ambient temperature (T_{A(MAX)}). Therefore, in situations where the ADP8861 is exposed to poor thermal resistance and high power dissipation (P_D), the maximum ambient temperature may need to be derated. In these cases, the maximum ambient temperature can be calculated with the following equation:

$$T_{A(MAX)} = T_{J(MAX)} - (\theta_{JA} \times P_{D(MAX)})$$

THERMAL RESISTANCE

θ_{JA} (junction to air) is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages. The θ_{JA}, θ_{JB} (junction to board), and θ_{JC} (junction to case) are determined according to JESD51-9 on a 4-layer printed circuit board (PCB) with natural convection cooling. For the LFCSP package, the exposed pad must be soldered to GND.

Table 3. Thermal Resistance

Package Type	θ _{JA}	θ _{JB}	θ _{JC}	Unit
WLCSP	48	9	N/A ¹	°C/W
LFCSP	49.5	N/A ¹	5.3	°C/W

¹ N/A stands for not applicable.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

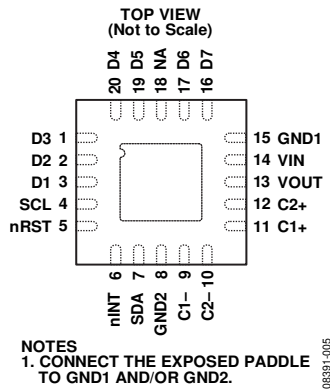


Figure 3. LFCSP Pin Configuration

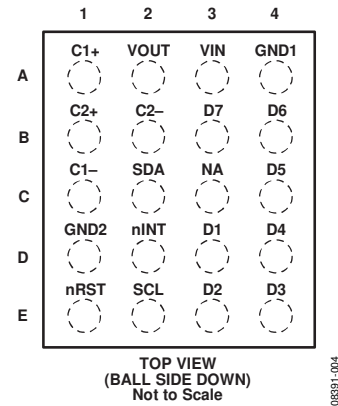


Figure 4. WLCSP Pin Configuration

Table 4. Pin Function Descriptions

Pin No.		Mnemonic	Description
LFCSP	WLCSP		
14	A3	VIN	Input Voltage, 2.5V to 5.5V.
3	D3	D1	LED Sink 1.
2	E3	D2	LED Sink 2.
1	E4	D3	LED Sink 3.
20	D4	D4	LED Sink 4.
19	C4	D5	LED Sink 5.
17	B4	D6	LED Sink 6.
16	B3	D7	LED Sink 7.
18	C3	NA	This pin is not used and must be connected to ground.
13	A2	VOUT	Charge Pump Output.
11	A1	C1+	Charge Pump C1+.
9	C1	C1-	Charge Pump C1-.
12	B1	C2+	Charge Pump C2+.
10	B2	C2-	Charge Pump C2-.
15	A4	GND1	Ground. Connect the exposed pad to GND1 and/or GND2.
8	D1	GND2	Ground. Connect the exposed pad to GND1 and/or GND2.
6	D2	nINT	Processor Interrupt (Active Low). Requires an external pull-up resistor. If this pin is not used, it can be left floating.
5	E1	nRST	Hardware Reset (Active Low). This pin resets the device to the default conditions. If not used, this pin must be tied above $V_{IH(MIN)}$.
7	C2	SDA	I ² C Serial Data. Requires an external pull-up resistor.
4	E2	SCL	I ² C Clock. Requires an external pull-up resistor.
21	Not applicable	EPAD	Exposed Paddle. Connect the exposed paddle to GND1 and/or GND2.

TYPICAL PERFORMANCE CHARACTERISTICS

V_{IN} = 3.6 V, SCL = 2.7 V, SDA = 2.7 V, nRST = 2.7 V, V_{D1:D7} = 0.4 V, C_{IN} = 1 μF, Capacitor C1 = 1 μF, Capacitor C2 = 1 μF, C_{OUT} = 1 μF, T_A = 25°C, unless otherwise noted.

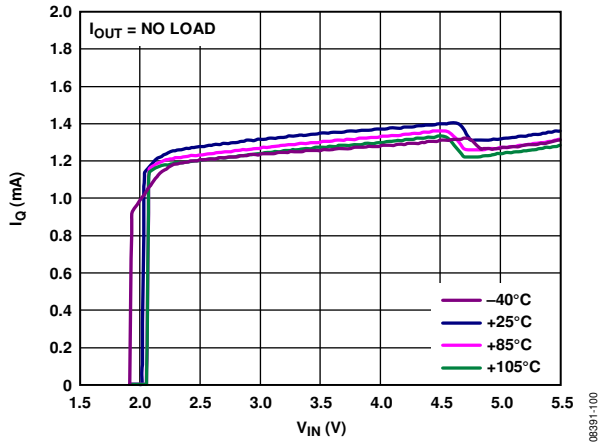


Figure 5. Typical Quiescent Current, G = 1x

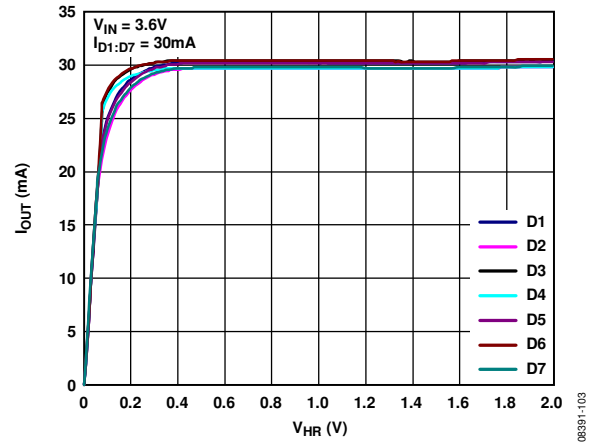


Figure 8. Typical Diode Current vs. Current Sink Headroom Voltage (V_{HR})

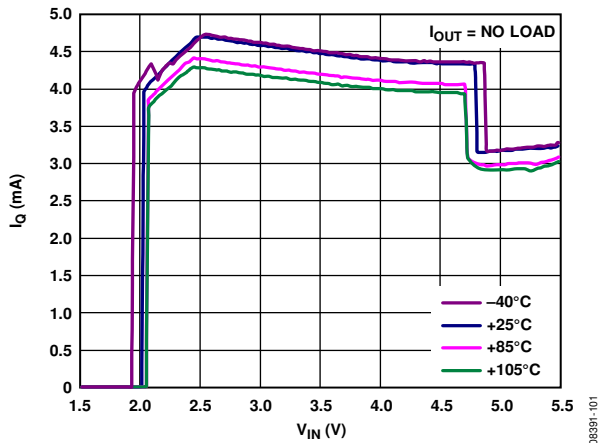


Figure 6. Typical Quiescent Current, G = 2x, I_{Q(ACTIVE)}

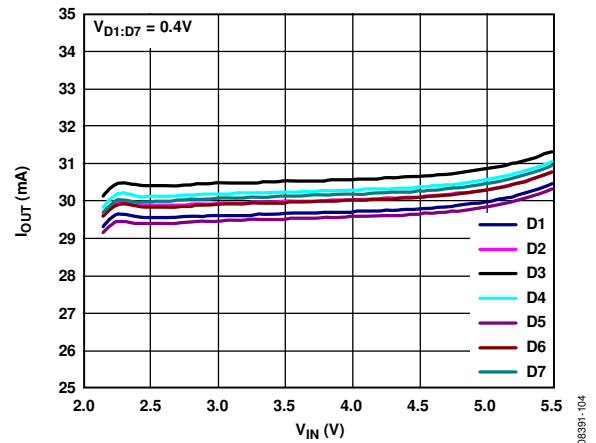


Figure 9. Typical Diode Current vs. V_{IN}

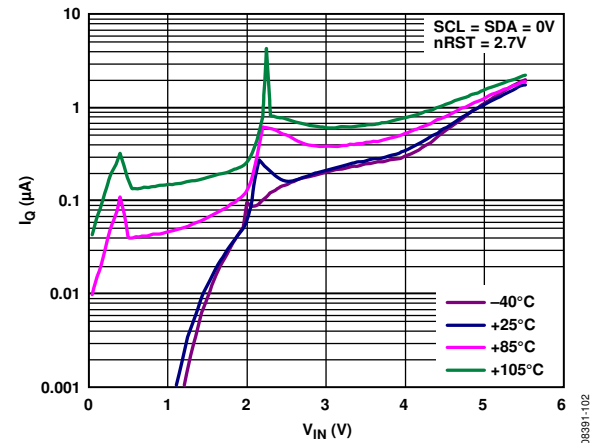


Figure 7. Typical Standby I_Q vs. V_{IN}

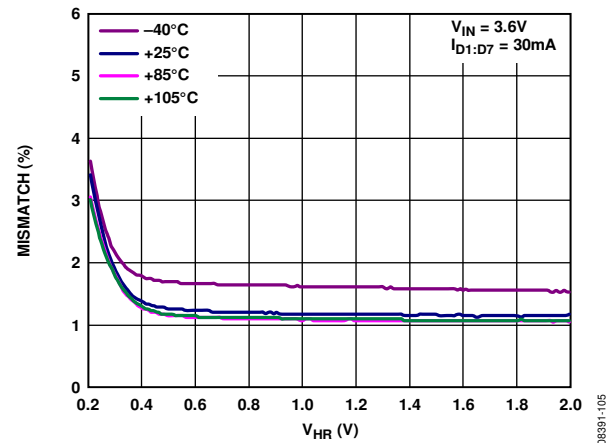


Figure 10. Typical Diode Matching vs. Current Sink Headroom Voltage (V_{HR})

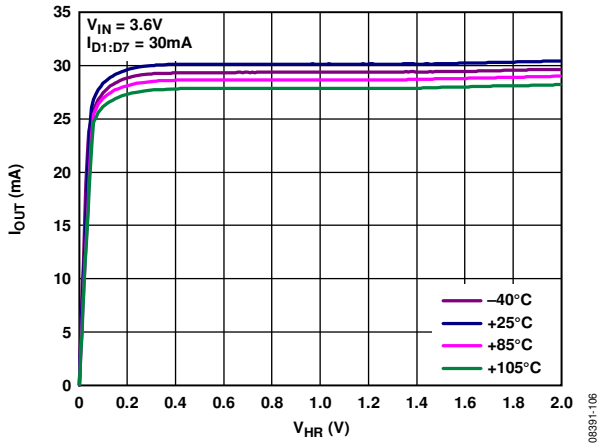


Figure 11. Typical Diode Current vs. Current Sink Headroom Voltage (V_{HR})

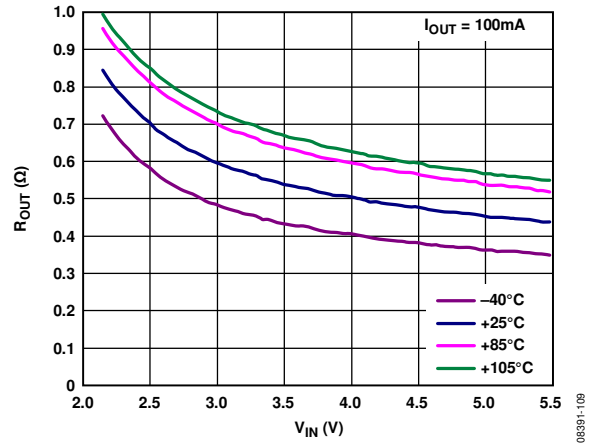


Figure 14. Typical R_{OUT} ($G = 1\times$) vs. V_{IN}

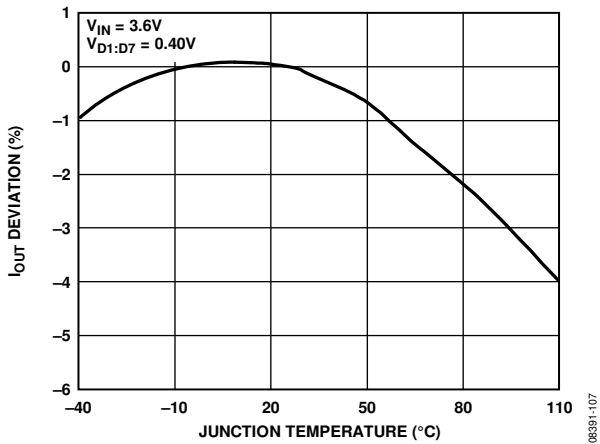


Figure 12. Typical Change In Diode Current vs. Temperature

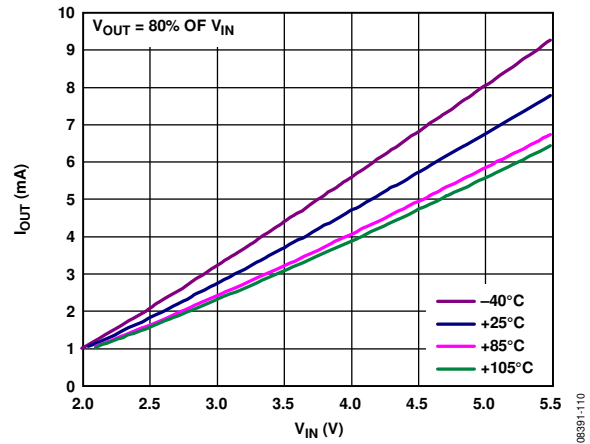


Figure 15. Typical Output Soft Start Current, I_{SS}

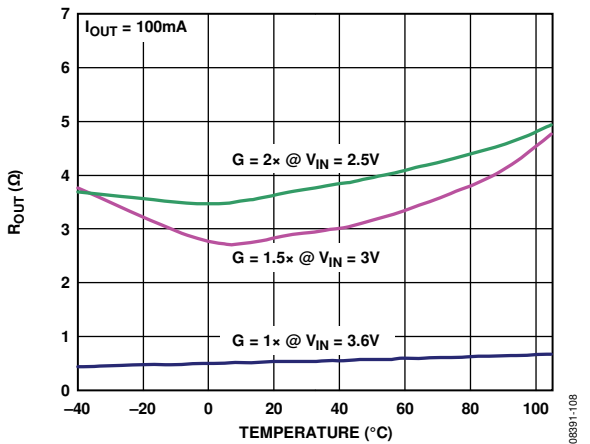


Figure 13. R_{OUT} vs. Temperature

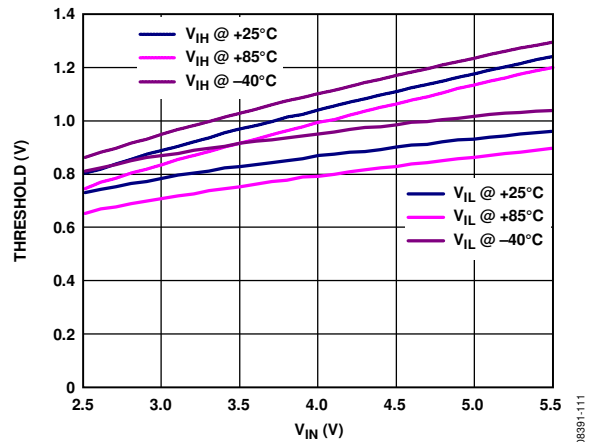


Figure 16. Typical I^2C Thresholds, V_{IH} and V_{IL}

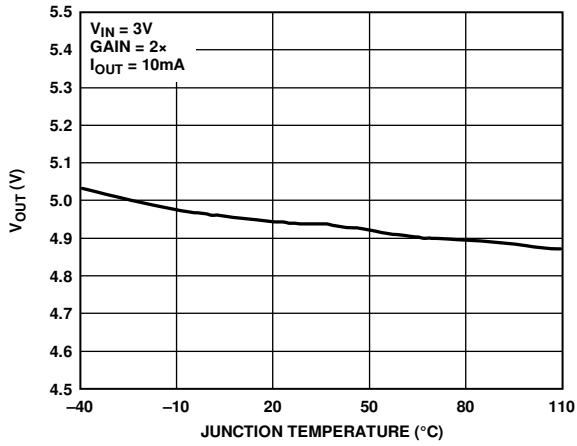


Figure 17. Typical Regulated Output Voltage ($V_{OUT(REG)}$)

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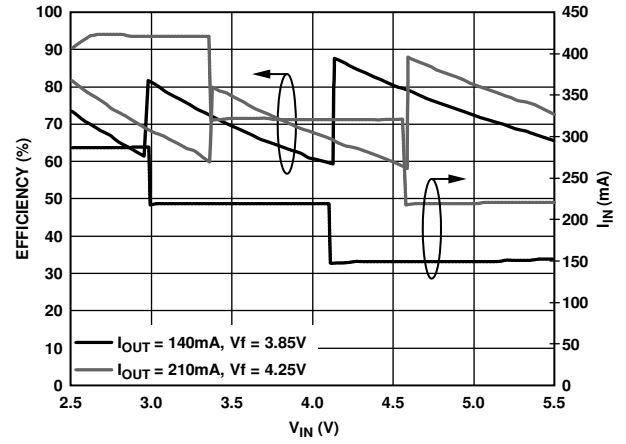


Figure 20. Typical Efficiency (High Vf Diode)

08391-116

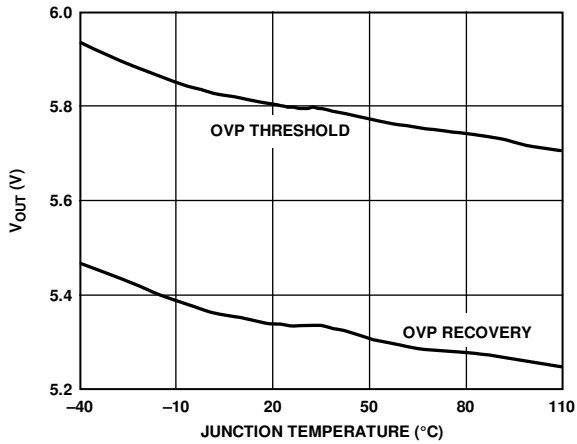


Figure 18. Typical Overvoltage Protection (OVP) Threshold

08391-114

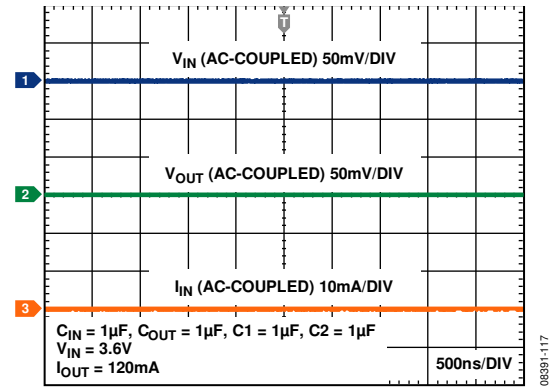


Figure 21. Typical Operating Waveforms, $G = 1\times$

08391-117

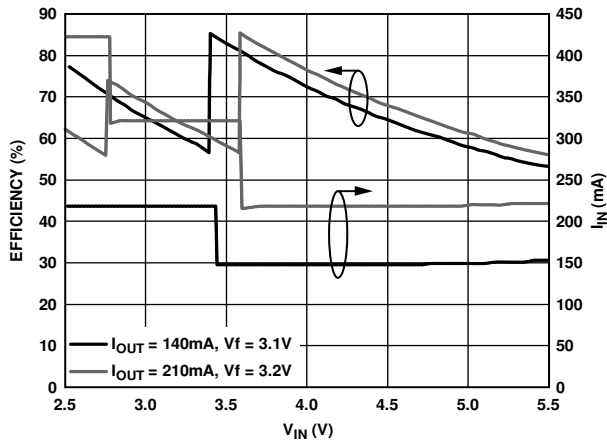


Figure 19. Typical Efficiency (Low Vf Diode)

08391-115

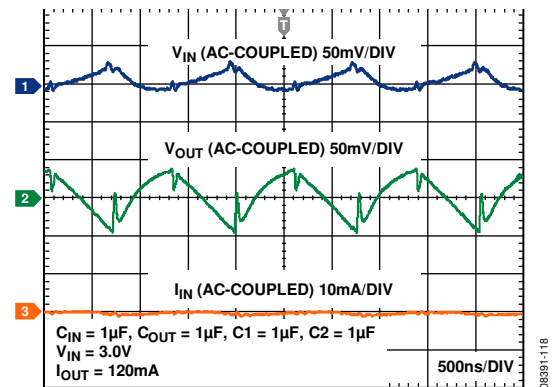


Figure 22. Typical Operating Waveforms, $G = 1.5\times$

08391-118

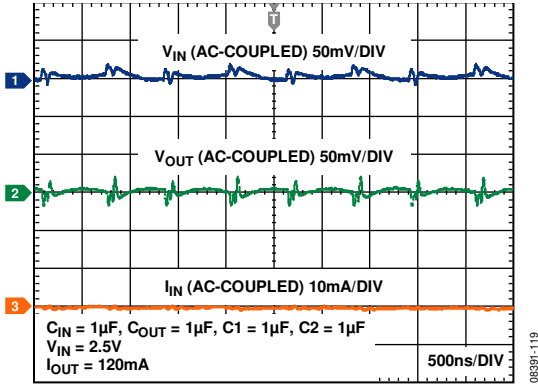


Figure 23. Typical Operating Waveforms, $G = 2\times$

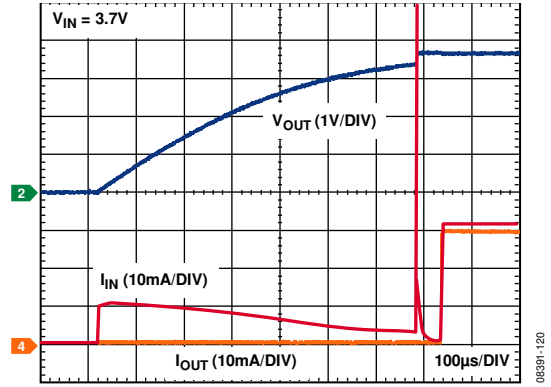


Figure 24. Typical Start-Up Waveform

POWER STAGE

Because typical white LEDs require up to 4 V to drive them, some form of boosting is required over the typical variation in battery voltage. The ADP8861 accomplishes this with a high efficiency charge pump capable of producing a maximum I_{OUT} of 240 mA over the entire input voltage range (2.5 V to 5.5 V). Charge pumps use the basic principle that a capacitor stores charge based on the voltage applied to it, as shown in the following equation:

$$Q = C \times V \tag{1}$$

By charging the capacitors in different configurations, the charge, and therefore the gain, can be optimized to deliver the voltage required to power the LEDs. Because a fixed charging and discharging combination must be used, only certain multiples of gain are available. The ADP8861 is capable of automatically optimizing the gain (G) from 1x, 1.5x, and 2x. These gains are accomplished with two capacitors (labeled C1 and C2 in Figure 25) and an internal switching network.

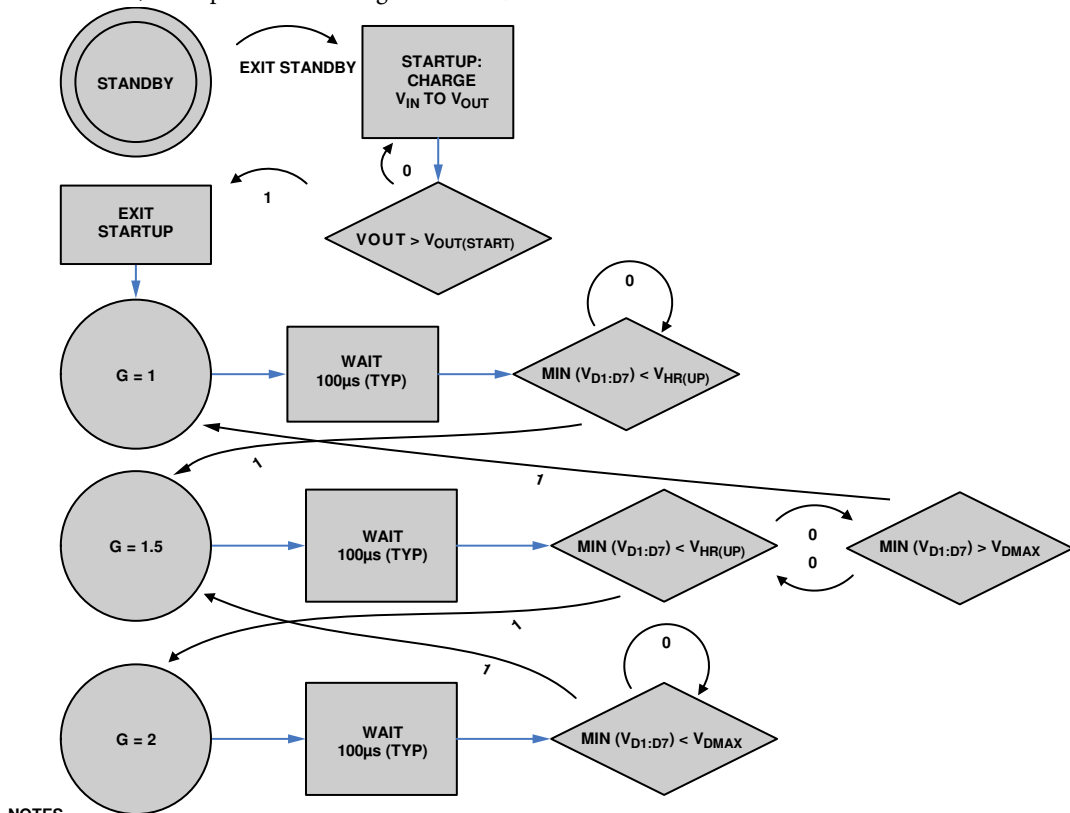
In $G = 1\times$ mode, the switches are configured to pass V_{IN} directly to V_{OUT} . In this mode, several switches are connected in parallel to minimize the resistive drop from input to output. In $G = 1.5\times$ and $2\times$ modes, the switches alternatively charge from the battery and discharge into the output. For $G = 1.5\times$, the capacitors are charged from V_{IN} in series and are discharged to V_{OUT} in parallel. For $G = 2\times$, the capacitors are charged from V_{IN}

in parallel and are discharged to V_{OUT} in parallel. In certain fault modes, the switches are opened and the output is physically isolated from the input.

Automatic Gain Selection

Each LED that is driven requires a current source. The voltage on this current source must be greater than a minimum headroom voltage (180 mV typical) to maintain accurate current regulation. The gain is automatically selected based on the minimum voltage (V_{DX}) at all of the current sources. At startup, the device is placed into $G = 1\times$ mode and the output charges to V_{IN} . If any $V_{D1:D7}$ level is less than the required headroom (180 mV), the gain is increased to the next step ($G = 1.5\times$). A 100 μs delay is allowed for the output to stabilize prior to the next gain switching decision. If there remains insufficient current sink headroom, then the gain is increased again to $2\times$. Conversely, to optimize efficiency, it is not desirable for the output voltage to be too high. Therefore, the gain reduces when the headroom voltage is great enough. This point (labeled V_{DMAX} in Figure 26) is internally calculated to ensure that the lower gain still results in ample headroom for all the current sinks. The entire cycle is illustrated in Figure 26.

Note that the gain selection criteria apply only to active current sources. If current sources have been deactivated through an I²C command (for example only five LEDs are used), then the voltages on the deactivated current sources are ignored.



NOTES
1. V_{DMAX} IS THE CALCULATED GAIN DOWN TRANSITION POINT.

Figure 26. State Diagram for Automatic Gain Selection

08391-012

Soft Start Feature

At startup (either from UVLO activation or fault/standby recovery), the output is first charged by I_{SS} (3.75 mA typical) until it reaches about 92% of V_{IN} . This soft start feature reduces the inrush current that is otherwise present when the output capacitance is initially charged to V_{IN} . When this point is reached, the controller enters $G = 1\times$ mode. If the output voltage is not sufficient, then the automatic gain selection determines the optimal point as defined in the Automatic Gain Selection section.

OPERATING MODES

There are four different operating modes: active, standby, shutdown, and reset.

Active Mode

In active mode, all circuits are powered up and in a fully operational state. This mode is entered when Bit nSTBY (in Register MDCR) is set to 1.

Standby Mode

Standby mode disables all circuitry except for the I²C receivers. Current consumption is reduced to less than 1 μ A. This mode is entered when the nSTBY bit is set to 0 or when the nRST pin is held low for more than 100 μ s (maximum). When standby is exited, a soft start sequence is performed.

Shutdown Mode

Shutdown mode disables all circuitry, including the I²C receivers. Shutdown occurs when V_{IN} is below the undervoltage thresholds. When V_{IN} rises above $V_{IN(START)}$ (2.05 V typical), all registers are reset and the part is placed into standby mode.

Reset Mode

In reset mode, all registers are set to their default values and the part is placed into standby. There are two ways to reset the part: by power-on reset (POR) or using the nRST pin. POR is activated any time that the part exits shutdown mode. After a POR sequence is complete, the part automatically enters standby mode.

After startup, the part can be reset by pulling the nRST pin low. As long as the nRST pin is low, the part is held in a standby state but no I²C commands are acknowledged (all registers are kept at their default values). After releasing the nRST pin, all registers remain at their default values, and the part remains in standby; however, the part does accept I²C commands.

The nRST pin has a 50 μ s (typical) noise filter to prevent inadvertent activation of the reset function. The nRST pin must be held low for this entire time to activate reset.

The operating modes function according to the timing diagram in Figure 27.

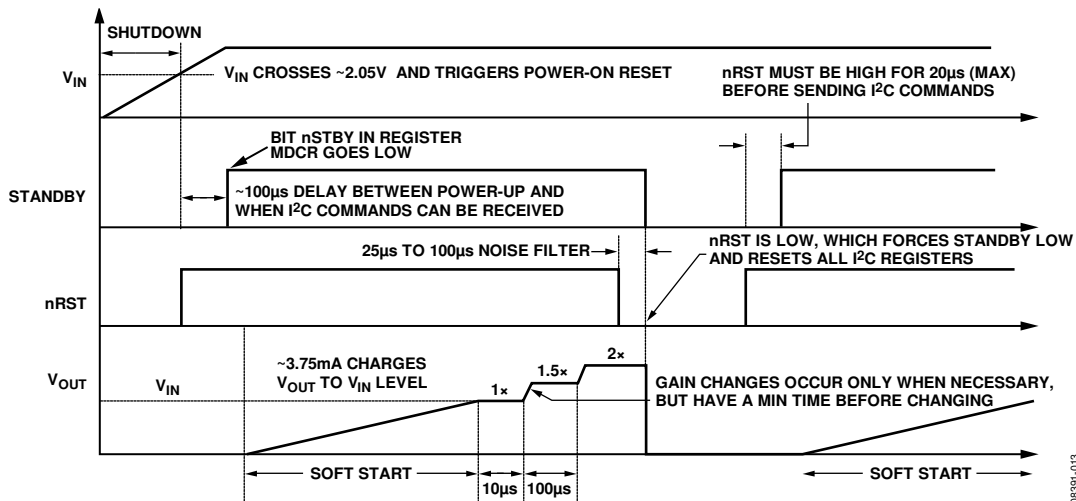


Figure 27. Typical Timing Diagram

08391-013

BACKLIGHT OPERATING LEVELS

The backlight can be operated at either the maximum level (Register 0x09) or the dim level (Register 0x0A). The backlight maximum and dim current settings are determined by a 7-bit code programmed by the user into these registers. The 7-bit resolution allows the user to set the backlight to one of 128 different levels between 0 mA and 30 mA.

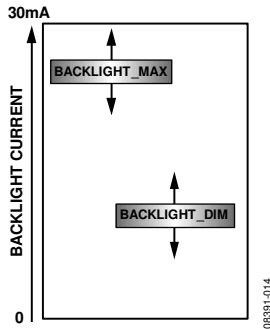


Figure 28. Backlight Operating Levels

The maximum and dim settings can be set between 0 mA and 30 mA; therefore, it is possible to program a dim setting that is greater than a maximum setting. For normal expected operation, ensure that the dim setting is programmed to be less than the maximum setting.

BACKLIGHT MAXIMUM AND DIM SETTINGS

The ADP8861 can implement two distinct algorithms to achieve a linear and a nonlinear relationship between input code and backlight current. The law bits in Register 0x04 are used to change between these algorithms.

By default, the ADP8861 uses a linear algorithm (law = 00), where the backlight current increases linearly for a corresponding increase in input code. Backlight current (in milliamperes) is determined by the following equation:

$$\text{Backlight Current (mA)} = \text{Code} \times (\text{Full-Scale Current}/127) \quad (2)$$

where:

Code is the input code programmed by the user.

Full-Scale Current is the maximum sink current allowed per LED (typically 30 mA).

The ADP8861 can also implement a nonlinear (square approximation) relationship between input code and backlight current level. In this case (law = 01), the backlight current (in milliamperes) is determined by the following equation:

$$\text{Backlight Current (mA)} = \left(\text{Code} \times \frac{\sqrt{\text{Full-Scale Current}}}{127} \right)^2 \quad (3)$$

Figure 29 shows the backlight current level vs. input code for both the linear and square law algorithms.

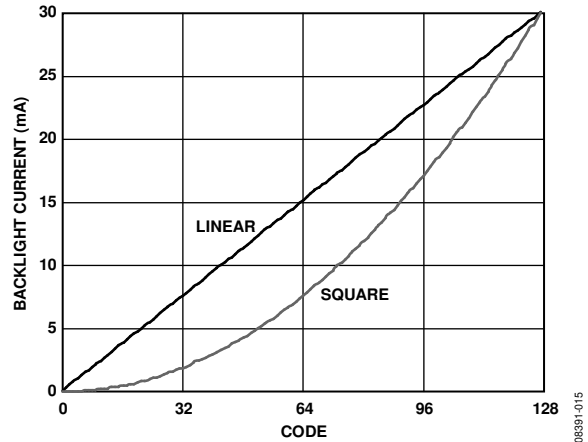


Figure 29. Backlight Current vs. Input Code

AUTOMATED FADE IN AND FADE OUT

The LED drivers are easily configured for automated fade in and fade out. Sixteen fade in and fade out rates can be selected via the I²C interface. Fade in and fade out rates range from 0.1 sec to 5.5 sec (per full-scale current, either 30 mA or 60 mA).

Table 5. Available Fade In and Fade Out Rates

Code	Fade Rate (in sec per Full-Scale Current)
0000	0.1 (disabled)
0001	0.3
0010	0.6
0011	0.9
0100	1.2
0101	1.5
0110	1.8
0111	2.1
1000	2.4
1001	2.7
1010	3.0
1011	3.5
1100	4.0
1101	4.5
1110	5.0
1111	5.5

The fade profile is based on the transfer law selected (linear, square, Cubic 10, or Cubic 11) and the delta between the actual current and the target current. Smaller changes in current reduce the fade time. For linear and square law fades, the fade time is given by

$$\text{Fade Time} = \text{Fade Rate} \times (\text{Code}/127) \quad (4)$$

where the Fade Rate is shown in Table 5.

The Cubic 10 and Cubic 11 laws also use the square law backlight currents derived from Equation 3; however, the time between each step is varied to produce a steeper slope at higher currents and a shallower slope at lower currents (see Figure 30).

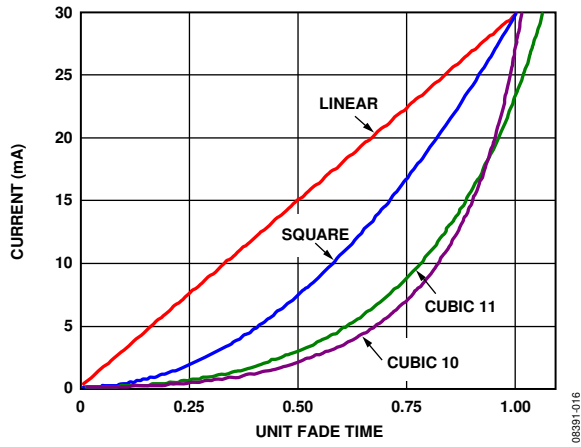


Figure 30. Comparison of the Dimming Transfers Laws

BACKLIGHT TURN ON/TURN OFF/DIM

With the device in active mode ($nSTBY = 1$), the backlight can be turned on using the BL_EN bit in Register 0x01. Before turning on the backlight, the user should ensure that the maximum and dim settings are programmed. The backlight turns on when BL_EN = 1. The backlight turns off when BL_EN = 0.

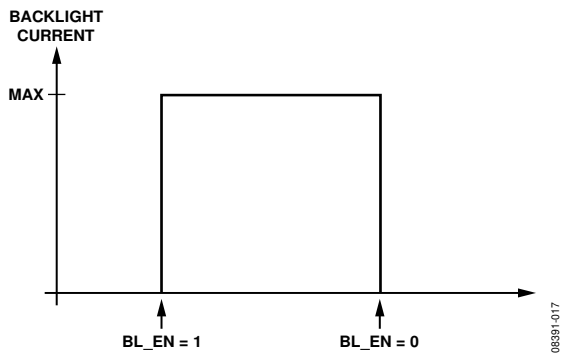


Figure 31. Backlight Turn On/Turn Off

While the backlight is on (BL_EN = 1), the user can change to the dim setting by programming DIM_EN = 1 in Register 0x01. If DIM_EN = 0, the backlight reverts to its maximum setting.

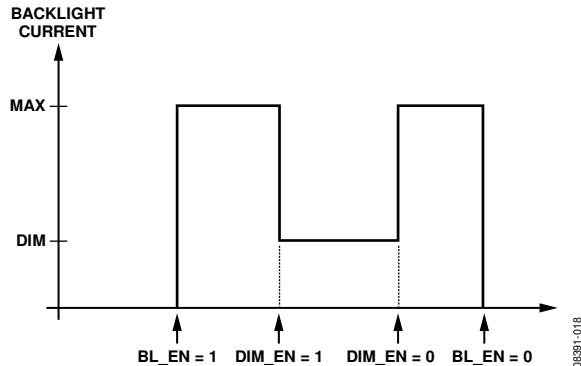


Figure 32. Backlight Turn On/Dim/Turn Off

AUTOMATIC DIM AND TURN OFF TIMERS

The user can program the backlight to dim automatically by using the DIMT bits in Register 0x07. The dim timer has 127 settings ranging from 1 sec to 127 sec. Program the dim timer (DIMT) before turning on the backlight. If BL_EN = 1, the backlight turns on to its maximum setting and the dim timer starts counting. When the dim timer expires, the internal state machine sets DIM_EN = 1, and the backlight enters its dim setting.

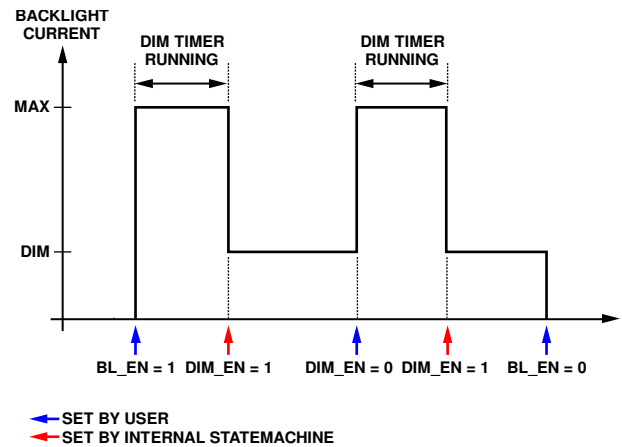


Figure 33. Dim Timer

If the user clears the DIM_EN bit, the backlight reverts to its maximum setting and the dim timer begins counting again. When the dim timer expires, the internal state machine again sets DIM_EN = 1, and the backlight enters its dim setting. The backlight can be turned off at any point during the dim timer countdown by clearing BL_EN.

The user can also program the backlight to turn off automatically by using the OFFT bits in Register 0x06. The off timer has 127 settings ranging from 1 sec to 127 sec. Program the off timer (OFFT) before turning on the backlight. If BL_EN = 1, the backlight turns on to its maximum setting and the off timer starts counting. When the off timer expires, the internal state machine clears the BL_EN bit, and the backlight turns off.

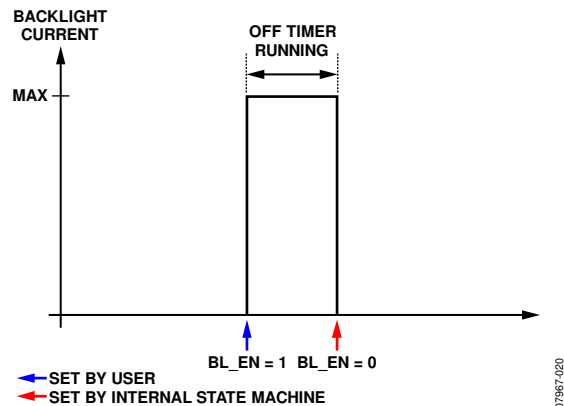


Figure 34. Off Timer

The backlight can be turned off at any point during the off timer countdown by clearing BL_EN.

The dim timer and off timer can be used together for sequential maximum-to-dim-to-off functionality. With both the dim and off timers programmed, and BL_EN asserted, the backlight turns on to its maximum setting, and when the dim timer expires, the backlight changes to its dim setting. When the off timer expires, the backlight turns off.

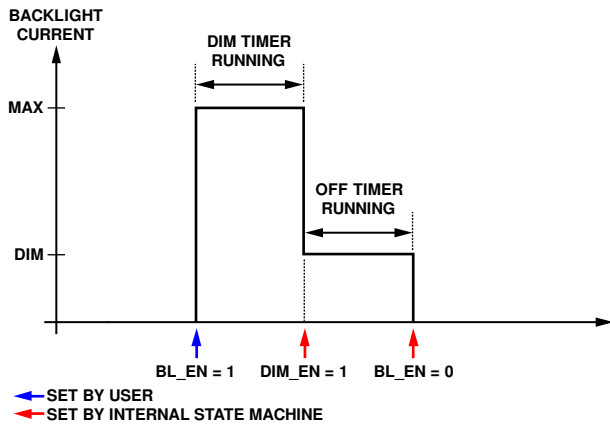


Figure 35. Dim and Off Timers Used Together

FADE OVERRIDE

A fade override feature (FOVR in Register CFGR (0x04)) enables the host to override the preprogrammed fade in or fade out settings. If FOVR is set and the backlight is enabled in the middle of a fade out process, the backlight instantly (within approximately 100 ms) returns to its prefade brightness level. Alternatively, if the backlight is fading in, reasserting BL_EN overrides the programmed fade in time, and the backlight instantly goes to its final fade value. This is useful for situations where a key is pressed during a fade sequence. However, if FOVR is cleared and the backlight is enabled in the middle of a fade process, the backlight gradually brightens from where it was interrupted (it does not go down to 0 and then comes back on).

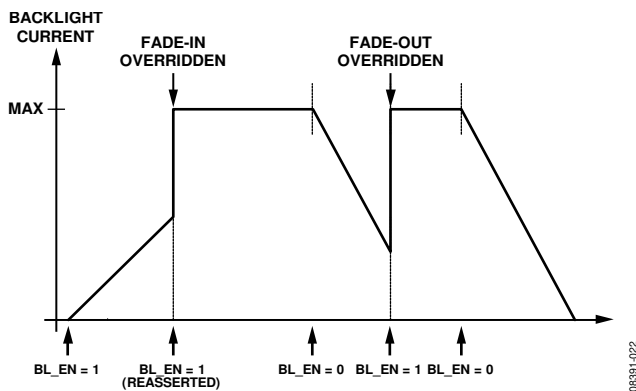


Figure 36. Fade Override Function (FOVR Is High)

INDEPENDENT SINK CONTROL

Each of the seven LEDs can be configured (in Register 0x05) to operate as either part of the backlight or to operate as an independent sink current (ISC). Each ISC can be enabled independently and has its own current level. All ISCs share the same fade in rates, fade out rates, and fade law.

The ISCs have additional timers to facilitate blinking functions. A shared on timer (SCON) used in conjunction with the off timers of each ISC (SC1_OFF, SC2_OFF, SC3_OFF, and SC4_OFF in Register 0x12, and SC5_OFF, SC6_OFF, and SC7_OFF in Register 0x11) allows the LED current sinks to be configured in various blinking modes. The on timer can be set to one of four different settings: 0.2 sec, 0.6 sec, 0.8 sec, or 1.2 sec. The off timers have four different settings: disabled, 0.6 sec, 1.2 sec, and 1.8 sec. Blink mode is activated by setting the off timers to any setting other than disabled.

Program all fade, on, and off timers before enabling any of the LED current sinks. If ISC_x is on during a blink cycle and SC_x_EN is cleared, the LED turns off (or fades to off if fade out is enabled). If ISC_x is off during a blink cycle and SC_x_EN is cleared, it stays off.

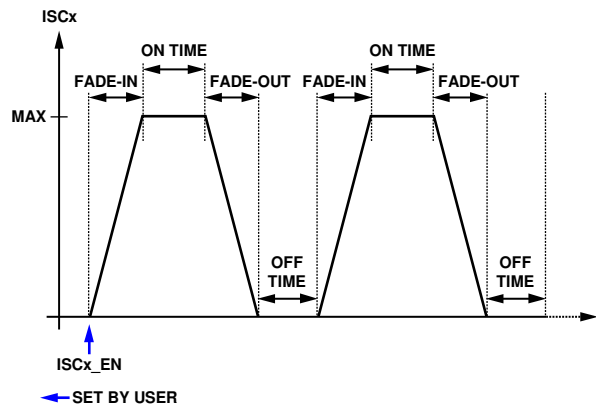


Figure 37. Independent Sink Blink Mode with Fading

SHORT-CIRCUIT PROTECTION MODE

The ADP8861 can protect against short circuits on the output (VOUT). Short-circuit protection (SCP) is activated at the point when VOUT < 55% of VIN. Note that SCP sensing is disabled during both startup and restart attempts (fault recovery). SCP sensing is reenabled 4 ms (typical) after activation. During a short-circuit fault, the device enters a low current consumption state and an interrupt flag is set. The device can be restarted at any time after receiving a short-circuit fault by simply rewriting nSTBY = 1. It then repeats another complete soft start sequence. Note that the value of the output capacitance (COUT) should be small enough to allow VOUT to reach approximately 55% (typical) of VIN within the 4 ms (typical) time. If COUT is too large, the device inadvertently enters short-circuit protection.

OVERVOLTAGE PROTECTION

Overvoltage protection (OVP) is implemented on the output. There are two types of overvoltage events: normal (no fault) and abnormal (from a fault or sudden load change).

Normal Overvoltage

In a normal (no fault) overvoltage, the output voltage approaches $V_{OUT(REG)}$ (4.9 V typical) during normal operation. This is not caused by a fault or load change, but it is simply a consequence of the input voltage times the gain reaching the same level as the clamped output voltage ($V_{OUT(REG)}$). To prevent this type of overvoltage, the ADP8861 detects when the output voltage rises to $V_{OUT(REG)}$. It then increases the effective R_{OUT} of the gain stage to reduce the voltage that is delivered. This effectively regulates V_{OUT} to $V_{OUT(REG)}$; however, there is a limit to the effect that this system can have on regulating V_{OUT} . It is designed only for normal operation and it is not intended to protect against faults or sudden load changes. When the output voltage is regulated to $V_{OUT(REG)}$, no interrupt is set and the operation is transparent to the LEDs and the overall application.

Abnormal Overvoltage

Because of the open-loop behavior of the charge pump as well as how the gain transitions are computed, a sudden load change or fault can abnormally force V_{OUT} beyond 6 V. This causes an abnormal overvoltage situation. If the event happens slowly enough, the system first tries to regulate the output to 4.9 V as in a normal overvoltage scenario. However, if this is not sufficient, or if the event happens too quickly, then the ADP8861 enters OVP mode when V_{OUT} exceeds the OVP threshold (typically 5.8 V). In OVP mode, only the charge pump is disabled to prevent V_{OUT} from rising too high. The current sources and all other device functionality remain intact. When the output voltage falls by about 500 mV (to 5.3 V typical), the charge

pump resumes operation. If the fault or load event recurs, the process may repeat. An interrupt flag is set at each OVP instance.

THERMAL SHUTDOWN/OVERTEMPERATURE PROTECTION

If the die temperature of the ADP8861 rises above a safe limit (150°C typical), the controllers enter thermal shutdown (TSD) protection mode. In this mode, most of the internal functions shut down, the part enters standby, and the TSD_INT interrupt (Register 0x02) is set. When the die temperature decreases below ~130°C, the part can be restarted. To restart the part, simply remove it from standby. No interrupt is generated when the die temperature falls below 130°C. However, if the software clears the pending TSD_INT interrupt and the temperature remains above 130°C, another interrupt is generated.

The complete state machine for these faults (SCP, OVP, and TSD) is shown in Figure 38.

INTERRUPTS

There are three interrupt sources available on the ADP8861 in Register 0x02.

- Overvoltage protection: The OVP_INT interrupt is generated when the output voltage exceeds 5.8 V (typical).
- Thermal shutdown circuit: An interrupt (TSD_INT) is generated when entering overtemperature protection.
- Short-circuit detection: SHORT_INT is generated when the device enters short-circuit protection mode.

The interrupt (if any) that appears on the nINT pin is determined by the bits mapped in Register INTR_EN (0x03). To clear an interrupt, write a 1 to the interrupt in the MDCR2 register (0x02) or reset the part. Reading the interrupt, or writing a 0, has no effect.

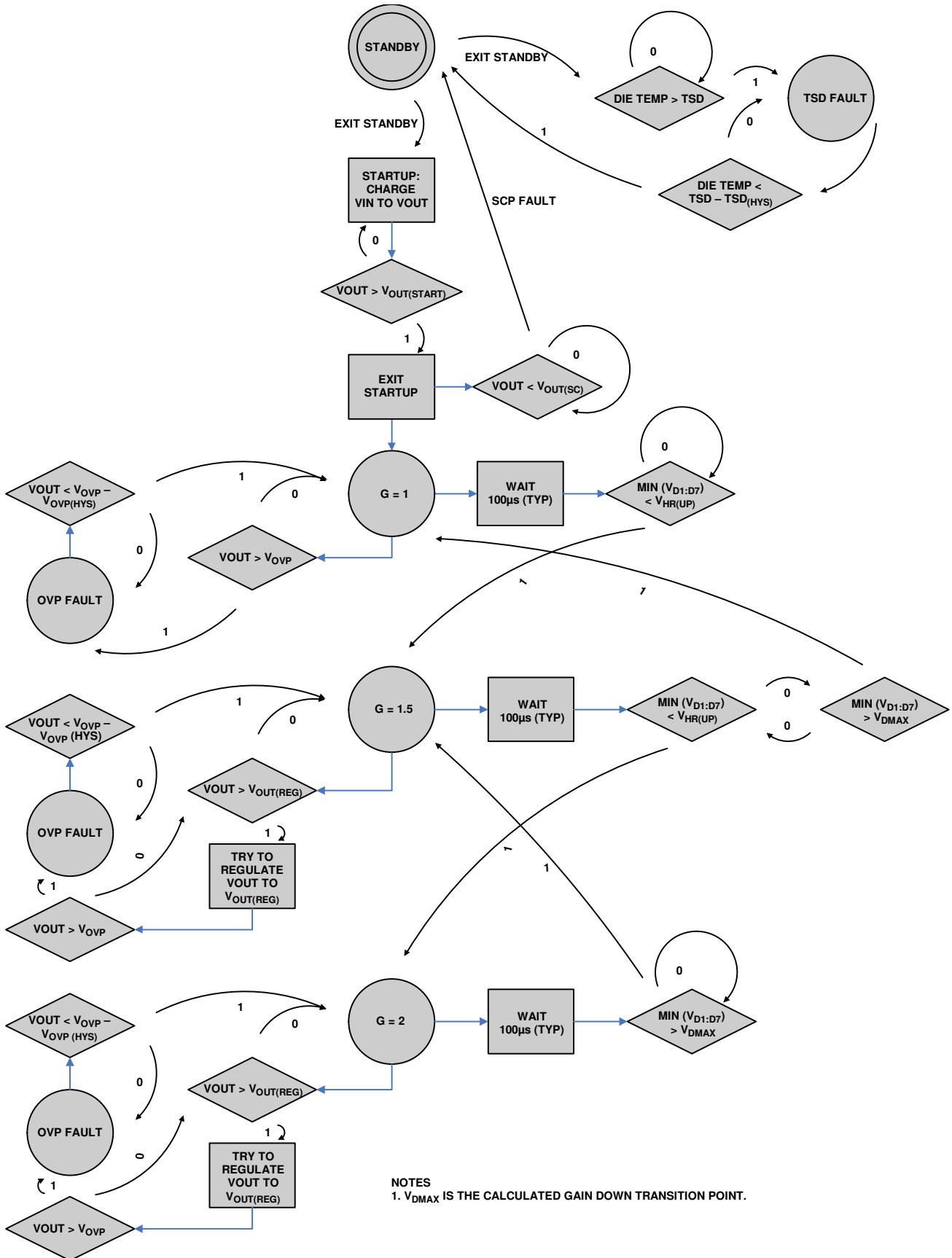


Figure 38. Fault State Machine

APPLICATIONS INFORMATION

The ADP8861 allows the charge pump to operate efficiently with a minimum of external components. Specifically, the user must select an input capacitor (C_{IN}), output capacitor (C_{OUT}), and two charge pump fly capacitors (C1 and C2). C_{IN} should be 1 μF or greater. The value must be high enough to produce a stable input voltage signal at the minimum input voltage and maximum output load. A 1 μF capacitor for C_{OUT} is recommended. Larger values are permissible, but care must be exercised to ensure that V_{OUT} charges above 55% (typical) of V_{IN} within 4 ms (typical). See the Short-Circuit Protection Mode section for more details.

For best practice, it is recommended that the two charge pump fly capacitors be 1 μF ; larger values are not recommended, and smaller values may reduce the ability of the charge pump to deliver maximum current. For optimal efficiency, the charge pump fly capacitors should have low equivalent series resistance (ESR). Low ESR X5R or X7R capacitors are recommended for all four components. The use of fly capacitors sized 0402 and smaller is allowed, but the GDWN_DIS bit in Register 0x01 must be set. Minimum voltage ratings should adhere to the guidelines in Table 6.

Table 6. Capacitor Stress in Each Charge Pump Gain State

Capacitor	Gain = 1x	Gain = 1.5x	Gain = 2x
C_{IN}	V_{IN}	V_{IN}	V_{IN}
C_{OUT}	V_{IN}	$V_{IN} \times 1.5$ (max of 5.5 V)	$V_{IN} \times 2.0$ (max of 5.5 V)
C1	None	$V_{IN}/2$	V_{IN}
C2	None	$V_{IN}/2$	V_{IN}

Any color LED can be used if the V_f (forward voltage) is less than 4.1 V. However, using lower V_f LEDs reduces the input power consumption by allowing the charge pump to operate at lower gain states.

The equivalent circuit model for a charge pump is shown in Figure 39.

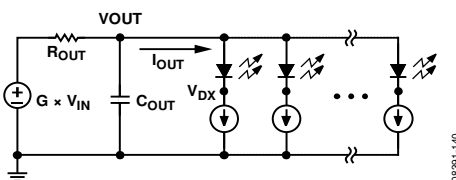


Figure 39. Charge Pump Equivalent Circuit Model

The input voltage is multiplied by the gain (G) and delivered to the output through an effective resistance (R_{OUT}). The output current flows through R_{OUT} and produces an IR drop to yield:

$$V_{OUT} = G \times V_{IN} - I_{OUT} \times R_{OUT}(G) \quad (5)$$

The R_{OUT} term is a combination of the $R_{DS(ON)}$ resistance for the switches used in the charge pump and a small resistance, which accounts for the effective dynamic charge pump resistance. The R_{OUT} level changes based upon the gain (the configuration of the switches). Typical R_{OUT} values are given in Table 1, Figure 13, and Figure 14.

V_{OUT} is also equal to the largest V_f of the LEDs used plus the voltage drop across the regulating current source. This gives

$$V_{OUT} = V_{f(MAX)} + V_{DX} \quad (6)$$

Combining Equation 5 and Equation 6 gives

$$V_{IN} = (V_{f(MAX)} + V_{DX} + I_{OUT} \times R_{OUT}(G))/G \quad (7)$$

Equation 7 is useful for calculating approximate bounds for the charge pump design.

DETERMINING THE TRANSITION POINT OF THE CHARGE PUMP

Consider the following design example where:

$$V_{f(MAX)} = 3.7 \text{ V}$$

$$I_{OUT} = 140 \text{ mA (7 LEDs at 20 mA each)}$$

$$R_{OUT} (G = 1.5\times) = 3 \Omega \text{ (obtained from Figure 13)}$$

At the point of a gain transition, $V_{DX} = V_{HR(UP)}$. Table 1 gives the typical value of $V_{HR(UP)}$ as 0.2 V. Therefore, the input voltage level when the gain transitions from 1.5x to 2x is

$$V_{IN} = (3.7 \text{ V} + 0.2 \text{ V} + 140 \text{ mA} \times 3 \Omega)/1.5 = 2.88 \text{ V}$$

LAYOUT GUIDELINES

Note the following layout guidelines:

- For optimal noise immunity, place the C_{IN} and C_{OUT} capacitors as close to their respective pins as possible. These capacitors should share a short ground trace. If the LEDs are a significant distance from the V_{OUT} pin, another capacitor on V_{OUT} , placed closer to the LEDs, is advisable.
- For optimal efficiency, place the charge pump fly capacitors (C1 and C2) as close to the part as possible.
- The ADP8861 does not distinguish between power ground and analog ground. Therefore, both ground pins can be connected directly together. It is recommended that these ground pins be connected at the ground for the input and output capacitors.
- The LFCSP package requires the exposed pad to be soldered at the board to the GND1 and/or GND2 pin(s).
- Unused diode pins (Pin D1 to Pin D7) can be connected to ground or to V_{OUT} , or remain floating. However, the unused diode current sinks must be disabled by setting them as independent sinks in Register 0x05 and then disabling them in Register 0x10. If they are not disabled, the charge pump efficiency may suffer.
- If the interrupt pin (nINT) is not used, connect it to ground or leave it floating. Never connect it to a voltage supply, except through a $\geq 1 \text{ k}\Omega$ series resistor.
- The ADP8861 has an integrated noise filter on the nRST pin. Under normal conditions, it is not necessary to filter the reset line. However, if the part is exposed to an unusually noisy signal, it is beneficial to add a small RC filter or bypass capacitor on this pin. If the nRST pin is not used, it must be pulled well above the $V_{IH(MIN)}$ level (see Table 1). Do not allow the nRST pin to float.

EXAMPLE CIRCUITS

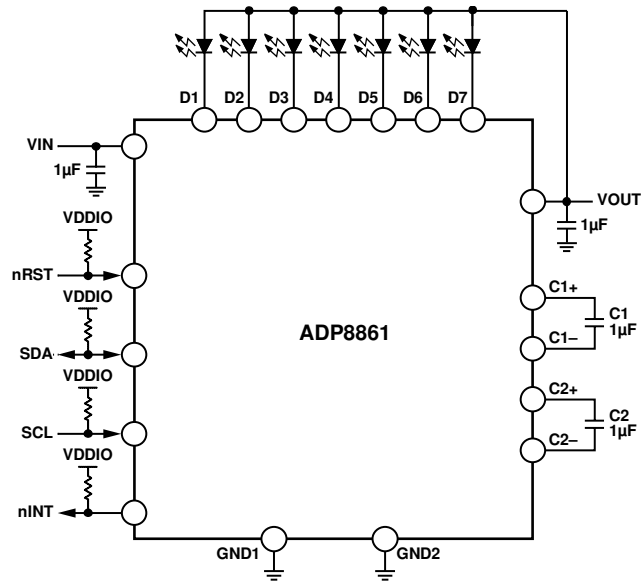


Figure 40. Generic Application Schematic

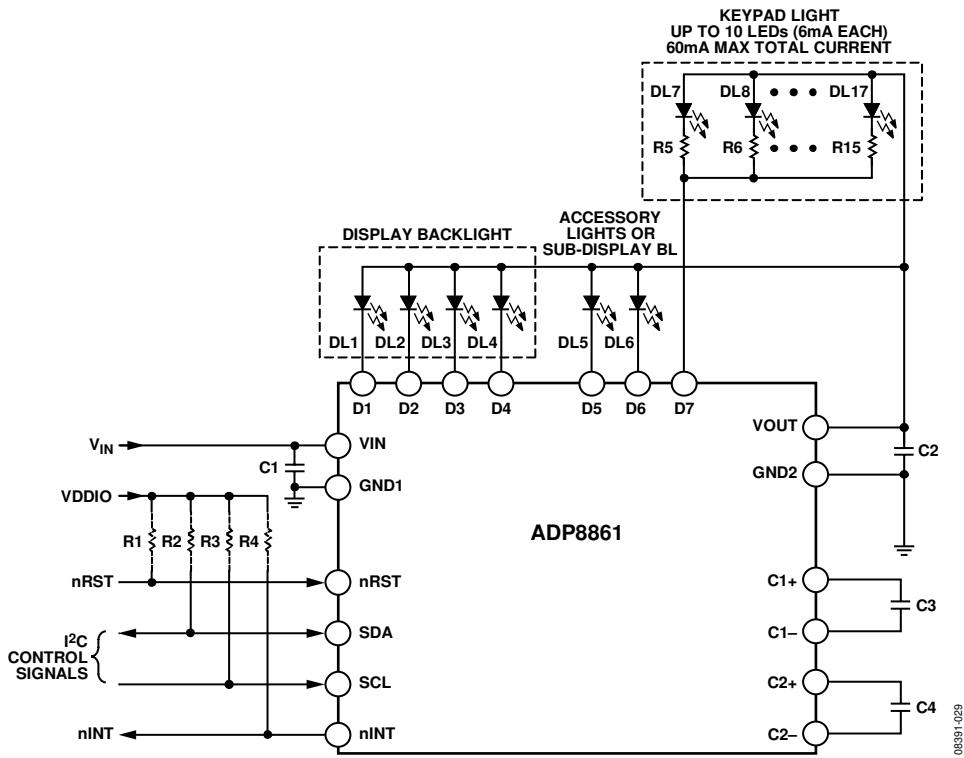


Figure 41. Application Schematic with Keypad Light Control

I²C PROGRAMMING AND DIGITAL CONTROL

The ADP8861 provides full software programmability to facilitate its adoption in various product architectures. The default I²C address is 0101010x (x = 0 during write, x = 1 during read). Therefore, the default write address is 0x54 and the read address is 0x55.

Note the following general behavior of registers:

- All registers are set to their default values during reset or after a UVLO event.
- All registers are read/write unless otherwise specified.
- Unused bits are read as zero.

Table 7 through Table 55 provide register and bit descriptions. The reset value for all bits in the bit map tables is all 0s, except in Table 9 (see Table 9 for its unique reset value). Wherever the acronym N/A appears in the tables, it means not applicable.

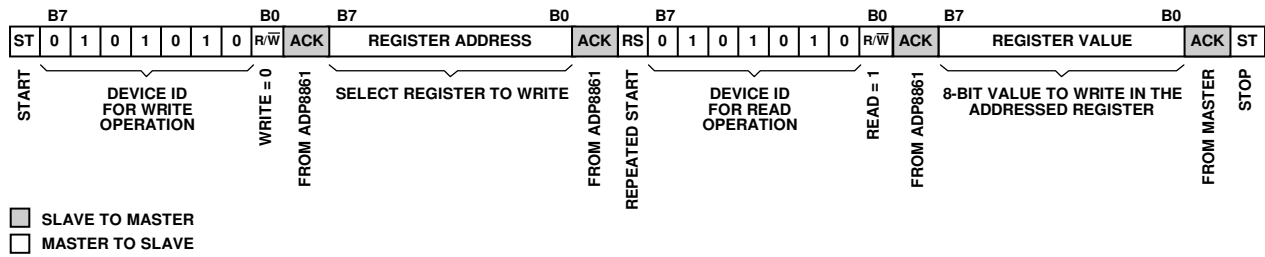


Figure 42. I²C Read Command Sequence

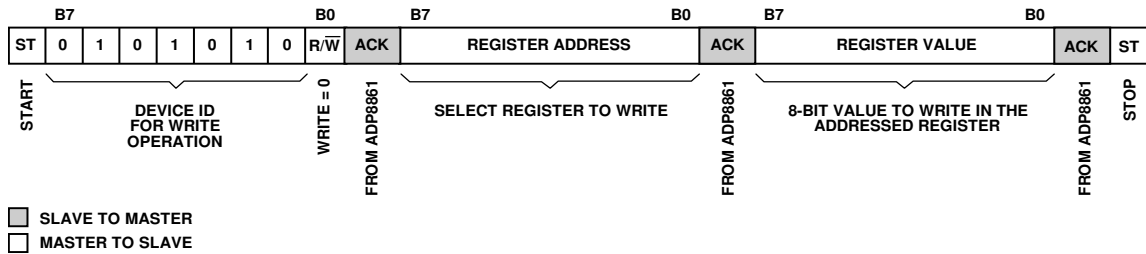


Figure 43. I²C Write Command Sequence

Table 7. Register Set Definitions

Address (Hex)	Register Name	Description
0x00	MFDVID	Manufacturer and device ID
0x01	MDCR	Device mode and status
0x02	MDCR2	Device mode and Status Register 2
0x03	INTR_EN	Interrupts enable
0x04	CFGR	Configuration register
0x05	BLSEN	Sink enable, backlight or independent
0x06	BLOFF	Backlight off timeout
0x07	BLDIM	Backlight dim timeout
0x08	BLFR	Backlight fade in and fade out rates
0x09	BLMX	Backlight maximum current
0x0A	BLDM	Backlight dim current
0x0B to 0x0E	Reserved	
0x0F	ISCFR	Independent sink current fade control register
0x10	ISCC	Independent sink current control register
0x11	ISCT1	Independent Sink Current Timer Register, LED[7:5]
0x12	ISCT2	Independent Sink Current Timer Register, LED[4:1]
0x13	ISCF	Independent sink current fade register
0x14	ISC7	Independent Sink Current, LED7
0x15	ISC6	Independent Sink Current, LED6
0x16	ISC5	Independent Sink Current, LED5
0x17	ISC4	Independent Sink Current, LED4
0x18	ISC3	Independent Sink Current, LED3
0x19	ISC2	Independent Sink Current, LED2
0x1A	ISC1	Independent Sink Current, LED1

Table 8. Register Map

Address (Hex)	Register Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	
0x00	MFDVID	Manufacturer ID				Device ID				
0x01	MDCR	Reserved	INT_CFG	nSTBY	DIM_EN	GDWN_DIS	SIS_EN	Reserved	BL_EN	
0x02	MDCR2	Reserved			SHORT_INT	TSD_INT	OVP_INT	Reserved		
0x03	INTR_EN	Reserved			SHORT_IEN	TSD_IEN	OVP_IEN	Reserved		
0x04	CFGR	Reserved					Law		FOVR	
0x05	BLSN	Reserved	D7EN	D6EN	D5EN	D4EN	D3EN	D2EN	D1EN	
0x06	BLOFF	Reserved	OFFT							
0x07	BLDIM	Reserved	DIMT							
0x08	BLFR	BL_FO				BL_FI				
0x09	BLMX	Reserved	BL_MC							
0x0A	BLDM	Reserved	BL_DC							
0x0B to 0x0E	N/A	Reserved								
0x0F	ISCFR	Reserved						SC_LAW		
0x10	ISCC	Reserved	SC7_EN	SC6_EN	SC5_EN	SC4_EN	SC3_EN	SC2_EN	SC1_EN	
0x11	ISCT1	SCON		SC7_OFF		SC6_OFF		SC5_OFF		
0x12	ISCT2	SC4_OFF		SC3_OFF		SC2_OFF		SC1_OFF		
0x13	ISCF	SCFO				SCFI				
0x14	ISC7	SCR	SCD7							
0x15	ISC6	Reserved	SCD6							
0x16	ISC5	Reserved	SCD5							
0x17	ISC4	Reserved	SCD4							
0x18	ISC3	Reserved	SCD3							
0x19	ISC2	Reserved	SCD2							
0x1A	ISC1	Reserved	SCD1							

Manufacturer and Device ID (MFDVID)—Register 0x00

Multiple device revisions are tracked by the device ID field. This is a read-only register.

Table 9. MFDVID Bit Map

Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Manufacturer ID				Device ID			
0	1	0	0	0	0	0	0

Mode Control Register (MDCR)—Register 0x01

Table 10. MDCR Bit Map

Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Reserved	INT_CFG	nSTBY	DIM_EN	GDWN_DIS	SIS_EN	Reserved	BL_EN

Table 11. Bit Descriptions for the MDCR Register

Bit Name	Bit No.	Description
N/A	7	Reserved.
INT_CFG	6	Interrupt configuration. 1 = processor interrupt deasserts for 50 μ s and reasserts with pending events. 0 = processor interrupt remains asserted if the host tries to clear the interrupt while there is a pending event.
nSTBY	5	1 = device is in active mode. 0 = device is in standby mode; only the I ² C interface is enabled.
DIM_EN	4	DIM_EN is set by the hardware after a dim timeout. The user can also force the backlight into dim mode by asserting this bit. Dim mode can only be entered if BL_EN is also enabled. 1 = backlight is operating at the dim current level (BL_EN must also be asserted). 0 = backlight is not in dim mode.
GDWN_DIS	3	1 = the charge pump does not switch down in gain until all LEDs are off. The charge pump switches up in gain as needed. This feature is useful if the ADP8861 charge pump is used to drive an external load. This feature must be used when utilizing small fly capacitors (0402 or smaller). 0 = the charge pump automatically switches up and down in gain. This provides optimal efficiency, but is not suitable for driving loads that are not connected through the ADP8861 diode drivers. Additionally, the charge pump fly capacitors should be low ESR and sized 0603 or greater.
SIS_EN	2	Synchronous independent sinks enable. 1 = enables all LED current sinks designated as independent sinks. This bit has no effect if any of the SCx_EN bits in Register 0x10 are set. 0 = disables all LED current sinks designated as independent sinks. This bit has no effect if any of the SCx_EN bits in Register 0x10 are set.
N/A	1	Reserved.
BL_EN	0	1 = backlight is enabled (nSTBY must also be asserted). 0 = backlight is disabled.